

Form PTO-1449			ATTY. DOCKET NO. 3430-0200P	APPLICATION NO. NEW 10/757521			
INFORMATION DISCLOSURE CITATION IN AN APPLICATION <small>(Use several sheets if necessary)</small>			APPLICANT Woong-Kwon KIM				
			FILING DATE January 15, 2003	GROUP Unassigned			
U.S. PATENT DOCUMENTS							
EXAMINER INITIAL	DOCUMENT NUMBER	KIND	DATE	NAME	CLASS	SUB CLASS	FILING DATE IF APPROPRIATE
<i>C</i>	US 5,994,721	A	1999-11-30	ZHONG et al			
	US 6,104,510	A		KASHIWAZAKI et al			
	US 6,104,459	A	2000-08-15	OIKE et al			
	US 5,724,107	A	1998-03-03	NISHIKAWA et al			
	US 6,211,928	B1	2001-04-03	OH et al			
	US 6,221,543	B1	2001-04-24	GUEHLER et al			
	US 5,994,721	A	1999-11-30	ZHONG et al			
	US 6,162,510	A	2000-12-19	KASHIWAZAKI et al			
	US 6,297,862	B1	2001-10-02	MURADE			
	US 6,166,786	A	2000-12-26	OHKUBO et al			
	US 6,327,006	B1	2001-12-04	SATO et al			
	US 6,281,955	B1	2001-08-28	MIDORIKAWA et al			
<i>C</i>	US 6,111,623	A	2000-08-29	SATO			
FOREIGN PATENT DOCUMENTS							
Office	DOCUMENT NUMBER	Kind	DATE	COUNTRY	CLASS	SUB CLASS	TRANSLATION
							YES
OTHER DOCUMENTS <small>(Include Name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.) date, page(s), volume-issue number(s), publisher, city and/or country where published.)</small>							
<i>C</i>	Pichon et al; "Low temperature unhydrogenated in-situ doped polysilicon thin film transistors: Toward a technology for flat panel displays"; Thin Solid Film, Vol. 296, pages 133-136, 1997.						
EXAMINER	Hoan Nguyen			DATE CONSIDERED	8/31/04		
<small>EXAMINER: Initial if citation considered, whether or not citation is in conformance with M.P.E.P. 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.</small>							